

# Green Laser Diode

## **Application**

Industrial use / Biomedical

### **Property**

Wavelength  $\lambda=520 \text{nm}$ 

Output Power = 60mW

Package Type =  $\phi$  5.6mm

#### Introduction

Egismos currently markets InGaN-based green laser diodes 515-520nm wavelengths range. The low operating current and high temperature of the laser diodes are achieved through using misoriented substrate and MQW (Strain compensated) active layer. Egismos laser diodes are highly rated in a broad range of applications including, but not limited to, laser pointers, green lasers, blue laser DVD, laser barcode scanners, diode laser equipments, medical instruments and aerospace applications.



# Green Laser Diode Key features

Absolute Maximum Rating at Tc=25℃				
Items	Symbols	Values	Unit	
Optical Output Power	Po(CW)	60	mW	
Reverse Voltage	V	2	V	
Operating Temperature	То	-10~+60	$^{\circ}\!\mathbb{C}$	
Storage Temperature	Ts	-10~+70	°C	

Electrical and Optical Characteristics at Tc=25℃					C	
Item	Symbols	Min	Тур.	Max.	Unit	Condition
Optical Output Power	Ро	-	-	50	mW	-
Threshold Current	Ith	-	45	75	mA	-
Operating Current	lop	-	160	170	mA	Po=60mW
Operating Voltage	Vop	-	7.0	8.0	V	Po=60mW
Peak Wavelength	λр	510	520	530	nm	Po=60mW



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<u>EGISMOS</u>	520nm Laser Diode			D	<u>6-6-520-60</u>	
Beam Divergence	θ//	4	7	11	deg	Po=60mW
	θ	16	22	25	deg	Po=60mW

Electrical Connection(Bottom	Package Type		
View]			
Unit (mm) Bottom View	PD LD		
Package Drawing			
1.2±0.1	2.3±0.1 1.0±0.1 2.3±0.1 2.3±0.1 2.3±0.1		

Specifications are subject to change without notice.





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